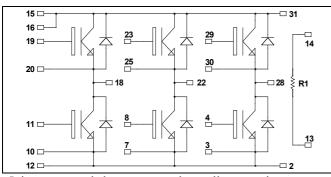
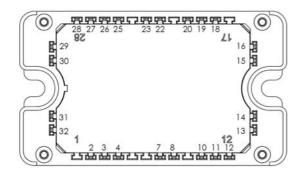


3 Phase bridge Trench + Field Stop IGBT3 Power Module $V_{CES} = 1200V$ $I_C = 25A$ @ $Tc = 80^{\circ}C$



It is recommended to connect a decoupling capacitor between pins 31 & 2 to reduce switching overvoltages, if DC Power is connected between pins 15, 16 & 12. Pins 15 & 16 must be shorted together.



Application

Motor control

Features

- Trench + Field Stop IGBT3
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Low leakage current
 - RBSOA and SCSOA rated
 - Kelvin emitter for easy drive
- Very low stray inductance
- Internal thermistor for temperature monitoring

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS compliant

All ratings @ $T_j = 25^{\circ}C$ unless otherwise specified

Absolute maximum ratings (Per IGBT)

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Voltage		1200	V
т	Continuous Collector Current	$T_C = 25^{\circ}C$	40	
$I_{\rm C}$	Continuous Conector Current	$T_C = 80$ °C	25	A
I_{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	50	
V_{GE}	Gate – Emitter Voltage		±20	V
P_D	Power Dissipation	$T_C = 25$ °C	156	W
RBSOA	Reverse Bias Safe Operation Area	$T_j = 125$ °C	50A @ 1150V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.



Electrical Characteristics (Per IGBT)

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				250	μΑ
V _{CE(sat)}	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25^{\circ}C$		1.7	2.1	V
		$I_{\rm C} = 25A \qquad T_{\rm j} = 125^{\circ} C$	$T_j = 125$ °C		2.0		V
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 1mA$		5.0	5.8	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V$, $V_{CE} = 0V$				400	nA

Dynamic Characteristics (Per IGBT)

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit	
Cies	Input Capacitance	$V_{GE} = 0V, V_{CE} = 25V$ f = 1MHz			1800		ьE
C_{res}	Reverse Transfer Capacitance				82		pF
T _{d(on)}	Turn-on Delay Time	Inductive Switching (25°C) $V_{GE} = \pm 15V$ $V_{Bus} = 600V$ $I_{C} = 25A$ $R_{G} = 27\Omega$			90		ns
T_{r}	Rise Time				30		
$T_{d(off)}$	Turn-off Delay Time				420		
T_{f}	Fall Time				70		
T _{d(on)}	Turn-on Delay Time	Inductive Switching (125°C) $V_{GE} = \pm 15V$ $V_{Bus} = 600V$ $I_{C} = 25A$ $R_{G} = 27\Omega$			90		ns
$T_{\rm r}$	Rise Time				50		
$T_{d(off)}$	Turn-off Delay Time				520		
T_{f}	Fall Time				90		
Eon	Turn-on Switching Energy	$\begin{aligned} V_{GE} &= \pm 15 V \\ V_{Bus} &= 600 V \\ I_C &= 25 A \\ R_G &= 27 \Omega \end{aligned}$	$T_j = 125$ °C		2.5		I
$E_{\rm off}$	Turn-off Switching Energy		$T_j = 125$ °C		2.9		mJ
R_{thJC}	Junction to Case Thermal Resistance					0.8	°C/W

Reverse diode ratings and characteristics (Per diode)

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Peak Repetitive Reverse Voltage					1200	V
I_{RM}	Reverse Leakage Current	V _R =1200V				100	μΑ
I_{F}	DC Forward Current		Tc = 80°C		30		A
		$I_F = 30A$			2.6	3.1	
V_{F}	Diode Forward Voltage	$I_F = 60A$	$I_F = 60A$		3.2		V
		$I_F = 30A$	$T_j = 125$ °C		1.8		
t _{rr}	Reverse Recovery Time		$T_j = 25^{\circ}C$		300		ns
		$I_F = 30A$	$T_j = 125$ °C		380		118
Qrr	Reverse Recovery Charge	$V_R = 800V$ di/dt = 200A/\(\mu\)s	$T_j = 25$ °C		360		C
		·	$T_j = 125$ °C		1700		пC
R_{thJC}	Junction to Case Thermal Resistance					1.2	°C/W



Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

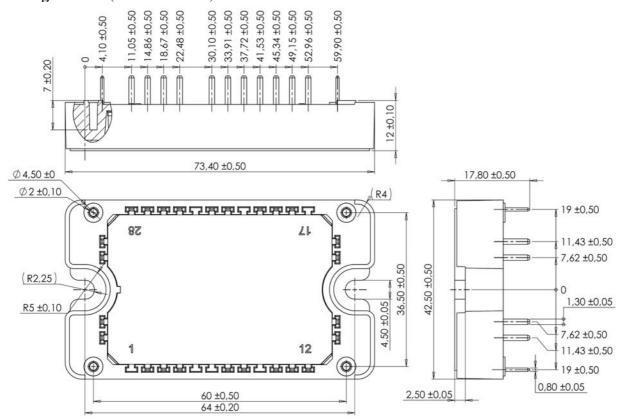
Symbol	Characteristic		Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C			50		kΩ
$\Delta R_{25}/R_{25}$				5		%
B _{25/85}	$T_{25} = 298.15 \text{ K}$			3952		K
$\Delta \mathrm{B/B}$		T _C =100°C		4		%

$$R_T = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$$
 T: Thermistor temperature R_T: Thermistor value at T

Thermal and package characteristics

Symbol	Characteristic			Min	Max	Unit
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000		V
$T_{\rm J}$	Operating junction temperature range			-40	150	
T_{JOP}	Recommended junction temperature under switching conditions			-40	T _J max -25	°C
T_{STG}	Storage Temperature Range			-40	125	C
$T_{\rm C}$	Operating Case Temperature			-40	125	
Torque	Mounting torque	To heatsink	M4	2	3	N.m
Wt	Package Weight				110	g

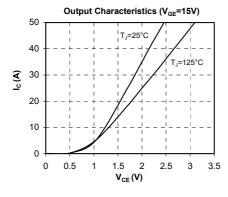
Package outline (dimensions in mm)

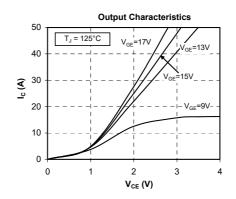


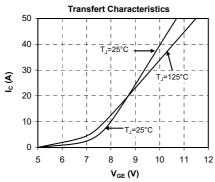
See application note 1906 - Mounting Instructions for SP3F Power Modules on www.microsemi.com

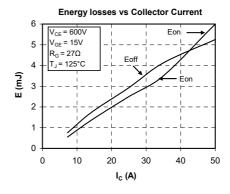


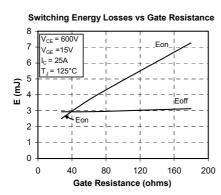
Typical Performance Curve

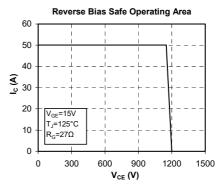


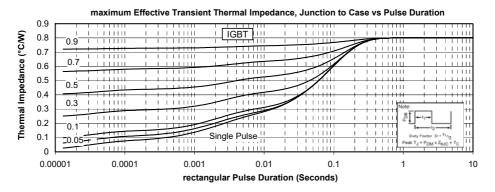




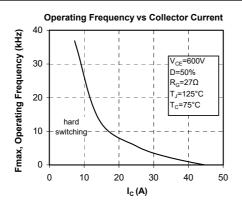


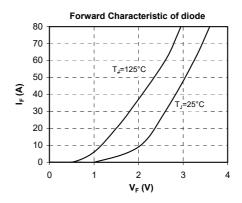


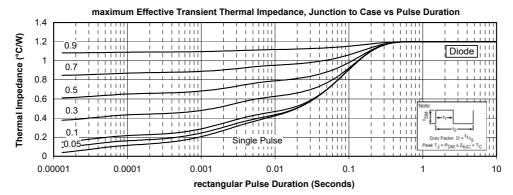














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